



PI6C5912016

16 Output LVPECL Fanout Buffer

Features

- → 16 differential LVPECL outputs
- → 2 selectable reference inputs support either single-ended or differential
- → Up to 2GHz output frequency
- → Ultra low additive phase jitter: < 0.01 ps (typ) (differential 156.25MHz, 12KHz to 20MHz integration range)
- → Low skew between outputs
- → Low delay from input to output (Tpd typ. < 1.7ns)
- → Separate Input output supply voltage for level shifting
- \rightarrow 2.5V / 3.3V power supply
- → Industrial temperature support
- → Package: TQFN-48

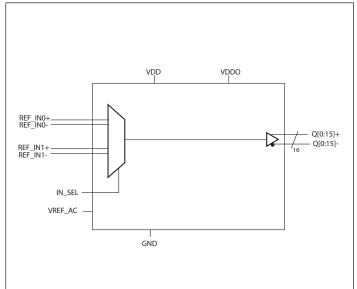
Description

The PI6C5912016 is a high performance LVPECL fanout buffer device which supports up to 2GHz frequency. This device is ideal for systems that need to distribute low jitter LVPECL clock signals to multiple destinations.

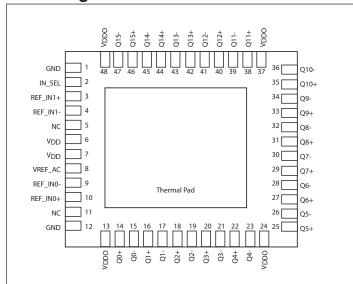
Applications

- → Networking systems including switches and routers
- → High frequency backplane based computing and telecom platforms

Block Diagram



Pin Configuration







Pin Description

Pin#	Pin Name	T	ype	Description
1, 12	GND	Power		Power supply ground
2	IN_SEL	Input	Pulldown	Input clock select. See Table 1 for function. LVCMOS/LVTTL interface levels.
3, 4	REF_IN1+ REF_IN1-	Input		Reference input 1. Accepts Differential or Single Ended inputs
5, 11	NC	-		No Connect
6, 7	VDD	Power		Core power supply
8	VREF_AC	Output		Bias voltage output.
9, 10	REF_IN0+	Input		Reference input 0. Accepts Differential or Single Ended inputs
13, 24, 37, 48	VDDO	Power		Output power supply
14, 15	Q0+ Q0-	Output		LVPECL output pair 0.
16, 17	Q1+ Q1-	Output		LVPECL output pair 1.
18, 19	Q2+ Q2-	Output		LVPECL output pair 2.
20, 21	Q3+ Q3-	Output		LVPECL output pair 3.
22, 23	Q4+ Q4-	Output		LVPECL output pair 4.
25, 26	Q5+ Q5-	Output		LVPECL output pair 5.
27, 28	Q6+ Q6-	Output		LVPECL output pair 6.
29, 30	Q7+ Q7-	Output		LVPECL output pair 7.
31, 32	Q8+ Q8-	Output		LVPECL output pair 8.
33, 34	Q9+ Q9-	Output		LVPECL output pair 9.
35, 36	Q10+ Q10-	Output		LVPECL output pair 10.





Pin Description Cont.

Pin #	Pin Name	Туре	Description		
38, 39	Q11+	Outmut	IVDECI output mais 11		
38, 39	Q11-	Output	LVPECL output pair 11.		
40 41	Q12+	October	LVDECL autumt main 12		
40, 41	Q12-	Output	LVPECL output pair 12.		
42, 43	Q13+	Output	LVPECL output pair 13.		
42, 43	Q13-	Output			
44 45	Q14+	Outmut	IVDECI output main 14		
44, 45	Q14-	Output	LVPECL output pair 14.		
46.47	Q15+	Outmut	IVDECL output main 15		
46, 47	Q15-	Output	LVPECL output pair 15.		
Thermal pad	-	-	Thermal pad. Connect to ground.		

Function Table

Table 1: Input select function

IN_SEL	Function
0	REF_IN0 is the selected reference input
1	REF_IN1 is the selected reference input
Open	No inputs selected. Outputs Hi-Z

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
C _{IN}	Input Capcitance			2		pF
R _{PULLDOWN}	Input Pulldown Resistor			200		kΩ
R _{PULLUP}	Input Pullup Resistor			200		kΩ

3





Maximum Ratings (Above which the useful life may be impaired. For user guidelines, not tested)

Storage temperature55 to +150°C
Supply Voltage to Ground Potential ($V_{\rm DD}, V_{\rm DDO}$)0.5 to +4.6V
Inputs (Referenced to GND)0.5 to $\rm V_{\rm DD} + 0.5 \rm V$
Clock Output (Referenced to GND)0.5 to $\rm V_{\rm DD} + 0.5 \rm V$
Latch up200mA
ESD Protection (Input)2000 V min (HBM)
ESD Protection (Input)1000 V min (CDM)

Note:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Power Supply Characteristics and Operating Conditions

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
V _{DD} Core Supply Voltage	Complex Voltage		3.135	3.3	3.465	V
		2.375	2.5	2.625	V	
	Output Supply Voltage		3.135	3.3	3.465	V
V_{DDO}			2.375	2.5	2.625	V
I_{EE}	Supply Internal Current			127	146	4
I_{DD}	Core Power Supply Current			91	105	mA
T_A	Ambient Operating Temperature		-40		85	°C

DC Electrical Specifications - Differential Inputs

Symbol	Parameter		Min.	Тур.	Max.	Units
I_{IH}	Input High current	$Input = V_{DD}$			20	uA
I _{IL}	Input Low current	Input = GND	-20			uA
V _{IH}	Input high voltage				V _{DD} +0.3	V
V _{IL}	Input low voltage		-0.3			V
V _{ID}	Input Differential Amplitude PK-PK		0.1			V
V _{CM}	Common model input voltage		GND + 0.5		V _{DD} -0.85	V
ISO _{MUX}	MUX isolation			-89		dBc





DC Electrical Specifications - LVCMOS Inputs

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
I_{IH}	Input High current	Input = V _{DD}			50	uA
I_{IL}	Input Low current	Input = GND	-50			uA
V_{IH}	Input high voltage	V _{DD} =3.3V	2.0		V _{DD} +0.3	V
V _{IL}	Input low voltage	V _{DD} =3.3V	-0.3		0.8	V
V _{IH}	Input high voltage	V _{DD} =2.5V	1.7		V _{DD} +0.3	V
V _{IL}	Input low voltage	V _{DD} =2.5V	-0.3		0.7	V

DC Electrical Specifications- LVPECL Outputs

Parameter	Description	Conditions	Min.	Тур.	Max.	Units
V _{OH}	Output High voltage		V _{DDO} -1.4		V_{DDO} -0.9	V
V _{OL} Output Low voltage	V _{DD} =2.5V	V _{DDO} -1.9		V _{DDO} -1.25	V	
	V _{DD} =3.3V	V _{DDO} -2.2		V _{DDO} -1.25	V	

AC Electrical Specifications – Differential Inputs

Parameter	Description	Conditions	Min.	Тур.	Max.	Units
F _{IN}	Clock input frequency				2000	MHz
V	Differential Input peak to peak voltage	$1.5 \text{GHz} \le F_{\text{IN}} \le 2 \text{ GHz}$	0.2		1.5	V
V _{INPP}		$F_{IN} \le 1.5 \text{ GHz}$	0.1		1.5	V
ER	Input Edge Rate		1.5			V/ns

AC Electrical Specifications – LVCMOS Inputs

Parameter	Description	Conditions	Min.	Тур.	Max.	Units
F _{IN}	Clock input frequency	REF_IN0+, REF_IN1+			200	MHz
V _{INPP}	LVCMOS Input peak to peak voltage		0.8		VDD	V
ER	Input Edge Rate		1.5			V/ns





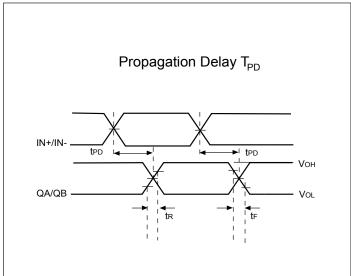
AC Electrical Specifications – LVPECL Outputs

Parameter	Description	Conditions	Min.	Typ.	Max.	Units
F _{OUT}	Clock output frequency	LVPECL			2000	MHz
$T_{\rm r}$	Output rise time	From 20% to 80%		150		ps
T_{f}	Output fall time	From 80% to 20%		150		ps
Todc	Output duty cycle		48		52	%
3.7	Output spring Single and ad	@1GHz to ≤2GHz	250		850	mV
V_{PP}	Output swing Single-ended	@ ≤1GHz	500		950	mV
	Buffer additive jitter RMS	156.25MHz, 12kHz to 20MHz		0.04	0.08	ps
T_j		156.25MHz, 10kHz to 1MHz		0.03	0.08	ps
T_{SK}	Output Skew			13	30	ps
T _{PD}	Propagation Delay			620	700	ps
Tod	Valid to HiZ				100	ns
Toe	HiZ to valid				100	ns
T _{P2P} Skew	Part to Part Skew ¹		-50		50	ps
V _{REF_AC}	Input bias voltage	$I_{AC} = 2mA$	V _{DD} -1.6		V _{DD} -1.1	V

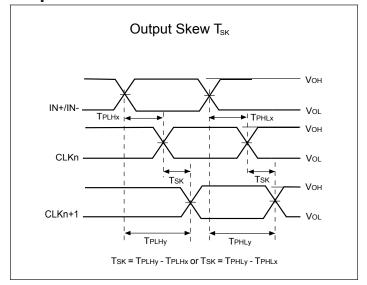




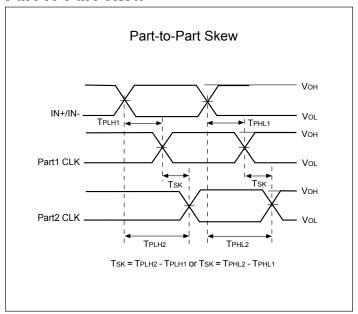
Propagation Delay



Output Skew



Part to Part Skew

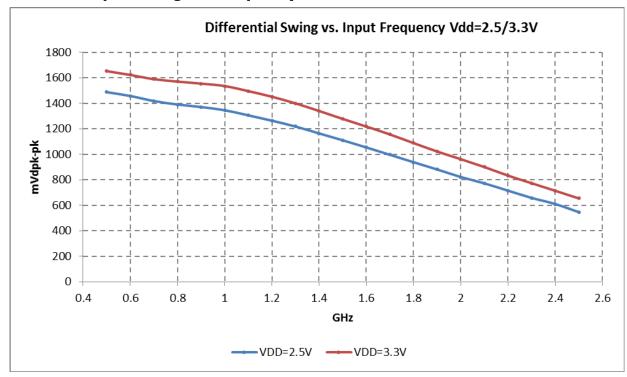


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LVPECL Output Swing vs. Frequency



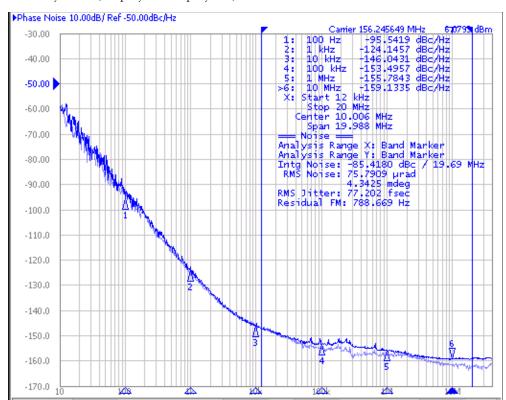
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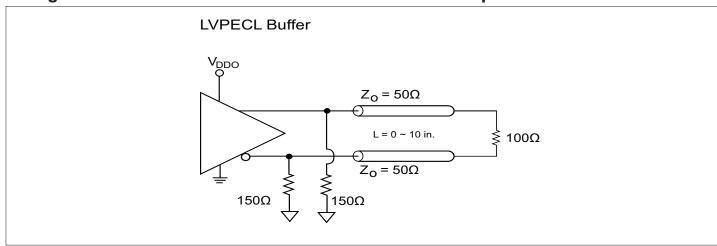


Phase Noise and Additive Jitter

Output phase noise (Dark Blue) vs Input Phase noise (light blue) Additive jitter = $\sqrt{\text{(Output jitter}^2 - Input jitter}^2)}$



Configuration Test Load Board Termination for LVPECL Outputs

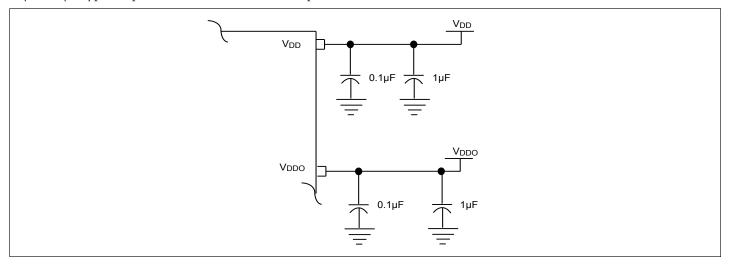




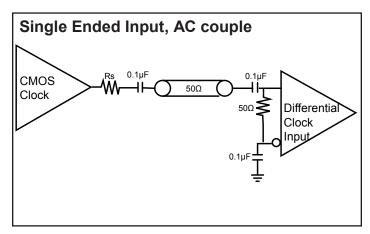


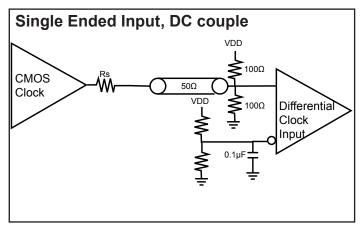
Power Supply Filtering Techniques

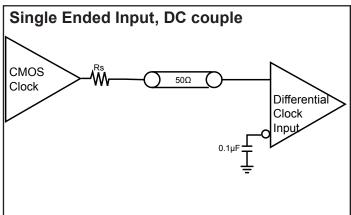
As in any high speed analog circuitry, the power supply pins are vulnerable to random noise. To achieve optimum jitter performance, power supply isolation is required. All power pins should be individually connected to the power supply plane through vias, and $0.1\mu F$ an $1\mu F$ bypass capacitors should be used for each pin.

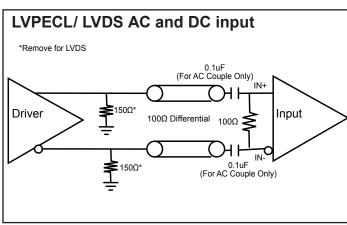


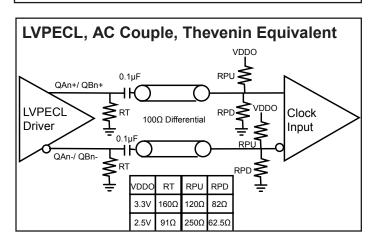


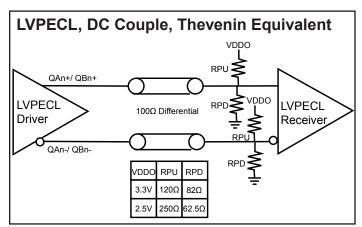








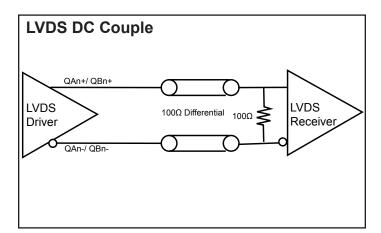


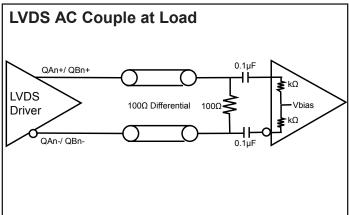


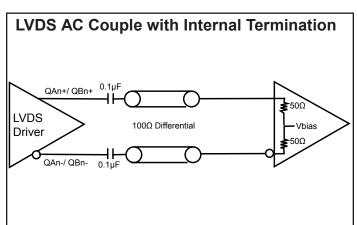
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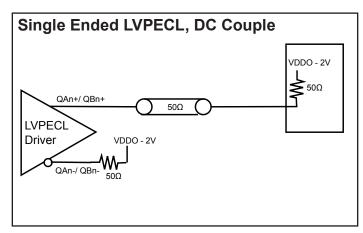


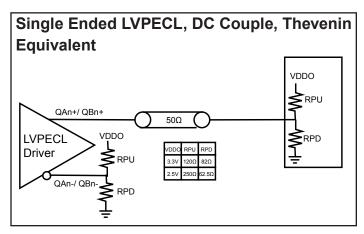


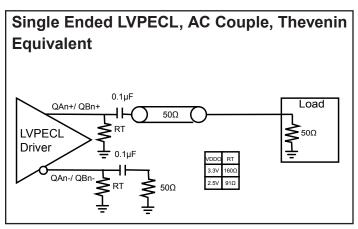












Thermal Information

Symbol	Description	Condition	
$\Theta_{_{ m JA}}$	Junction-to-ambient thermal resistance	Still air	23.65 °C/W
$\Theta_{ m JC}$	Junction-to-case thermal resistance		9.10 °C/W

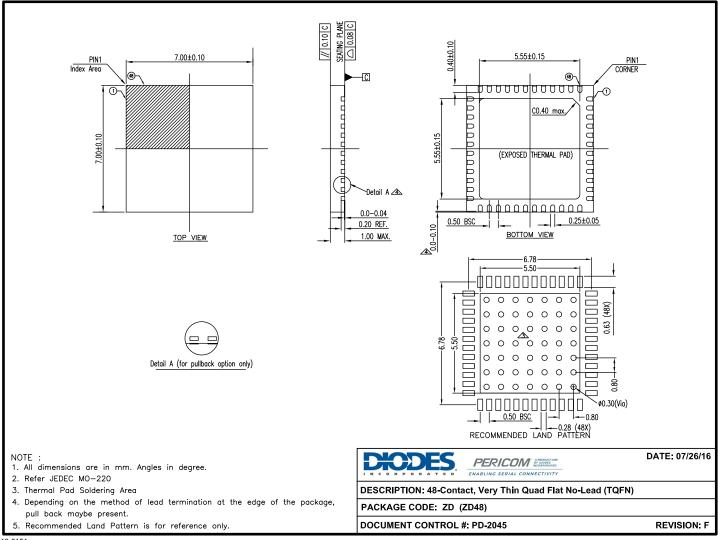
Part Marking

Top mark not available at this time. To obtain advance information regarding the top mark, please contact your local sales representative.





Packaging Mechanical: 48-TQFN (ZD)



For latest package info.

please check: http://www.diodes.com/design/support/packaging/pericom-packaging/packaging-mechanicals-and-thermal-characteristics/

Ordering Information

Ordering Code	Package Code	Package Type	Operating Temperature
PI6C5912016ZDIEX	ZD	48-Contact, Very Thin Quad Flat No-Lead (TQFN)	-40°C to 85°C

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free. Thermal characteristics can be found on the company web site at www.diodes.com/design/support/packaging/
- 3. E = Pb-free and Green
- 4. X suffix = Tape/Reel





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